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April 2018

FS8G - FS8M 8 A Standard Recovery Surface Mount Rectifiers

Features

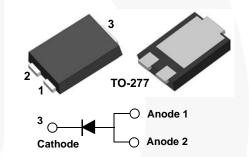
- Very High forward Surge Capability: I_{FSM} = 230 A
- Low Leakage Current: 0.37 μA at T_A = 25°C
- · Very Low Profile: Typical Height of 1.1 mm
- · Glass Passivated Junction
- · Lead Free in Compliance with EU RoHS 2011/65/EU Directive
- · Green Molding Compound as per IEC61249 Standard
- HBM (JEDEC A114) > 8 KV; CDM (JEDEC C101C) >

Applications

- · General-Purpose Applications
- · Reverse Polarity Protection
- Rectifications

Description

The FS8G to FS8M series offers breakthrough size and performance. It sinks 8 A DC forward current and provides up to 230 A surge current capability with only 0.37 µA reverse leakage current. All this ca pability is packed into a small, flat-lead, TO-277 package, optimized for space-constrained applications.



Ordering Information

Part Number	Top Mark	Package	Packing Method
FS8G	FS8G	TO-277 3L (No DAP Option)	Tape and Reel
FS8J	FS8J	TO-277 3L (No DAP Option)	Tape and Reel
FS8K	FS8K	TO-277 3L (No DAP Option)	Tape and Reel
FS8M	FS8M	TO-277 3L (No DAP Option)	Tape and Reel

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Value				Unit
		FS8G	FS8J	FS8K	FS8M	Offic
V_{RRM}	Maximum Repetitive Peak Reverse Voltage	400	600	800	1000	V
V _{RMS}	Maximum RMS Reverse Voltage	280	420	560	700	V
V_{DC}	DC Blocking Voltage	400	600	800	1000	V
I _{F(AV)}	Maximum Average Rectified Forward Current	8			Α	
I _{FSM}	Peak Forward Surge Current: 8.3 ms Single Half Sine-Wave Superimposed on Rated Load	230		А		
TJ	Operating Junction Temperature Range -55 to +150			°C		
T _{STG}	Storage Temperature Range	-55 to +150			°C	

Thermal Characteristics(1)

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Minimum Land Pattern	Maximum Land Pattern	Unit	
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance	100	40	°C/W	
ΨJL	Junction-to-Lead Thermal Characteristics, Thermocouple Soldered to Anode	20	12	°C/W	
	Junction-to-Lead Thermal Characteristics, Thermocouple Soldered to Cathode	6	5	C/VV	

Note:

1. The thermal resistances ($R_{\theta JA} \& \psi_{JL}$) are characterized with device mounted on the following FR4 printed circuit boards, as shown in Figure 1 and Figure 2. PCB size: 76.2 x 114.3 mm. Minimum land pattern size: 4.9 x 4.8 mm (big pattern, x1), 1.4 x 1.52 mm (small pattern, x2). Maximum land pattern size: 30 x 30 mm (pattern, x2). Force line trace size = 55 mils, sense line trace size = 4 mils.



Figure 1. Minimum Land Pattern of 2 oz Copper

Figure 2. Maximum Land Pattern of 2 oz Copper

Electrical Characteristics

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V _F	Forward Voltage	I _F = 8 A		0.951	1.1	V
		I _F = 8 A, T _A = 125°C		0.845		
I _R	DC Reverse Current	$V_R = V_{DC}$		0.37	5	μА
		V _R = V _{DC} , T _A = 125°C		84		
T _{rr}	Reverse Recovery Time	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		3.37		μs
CJ	Junction Capacitance	V _R = 0 V, f = 1 MHz		118		pF

Typical Performance Characteristics

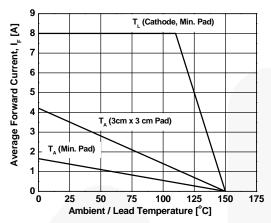


Figure 3. Forward Current Derating Curve

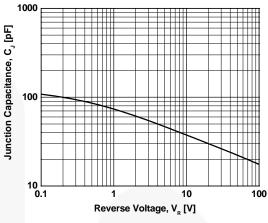


Figure 4. Typical Junction Capacitance

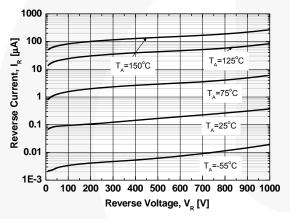


Figure 5. Typical Reverse Characteristics

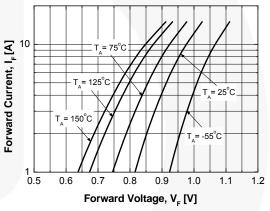


Figure 6. Typical Forward Characteristics

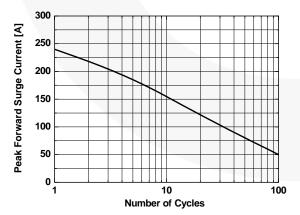
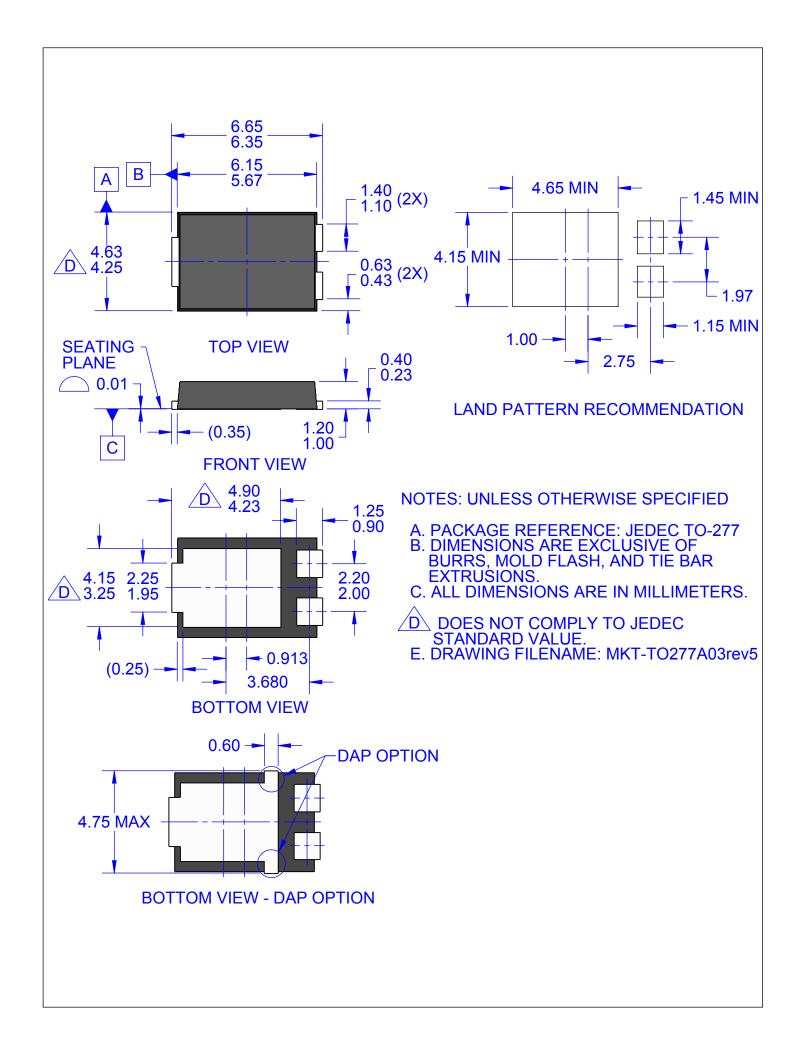


Figure 7. Maximum Non-repetitive Peak Forward Surge current



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